

| Standard Rectifier | V _{RRM} | = | 1600 V |
|--------------------|------------------|---|--------|
| | I _{FAV} | = | 150 A |
| | V _F | = | 1.05 V |
| | | | |

Single Diode

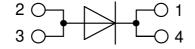
Part number

DMA150E1600NA



Backside: Isolated





Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase
- bridge configurations

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper
- internally DCB isolatedAdvanced power cycling

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

IXYS reserves the right to change limits, conditions and dimensions.



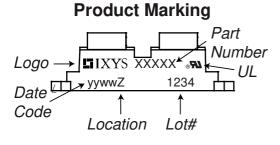
| Rectifier | | | | | Rating | 5 | |
|--------------------------|-----------------------------------|----------------------------|---------------------------------|------|--------|------|-------------------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V _{RSM} | max. non-repetitive reverse bloc | king voltage | $T_{VJ} = 25^{\circ}C$ | | | 1700 | V |
| V _{RRM} | max. repetitive reverse blocking | voltage | $T_{VJ} = 25^{\circ}C$ | | | 1600 | V |
| I _R | reverse current | $V_{R} = 1600 V$ | $T_{VJ} = 25^{\circ}C$ | | | 200 | μA |
| | | $V_{R} = 1600 V$ | $T_{vJ} = 150^{\circ}C$ | | | 3.5 | mA |
| V _F | forward voltage drop | I _F = 150 A | $T_{VJ} = 25^{\circ}C$ | | | 1.15 | V |
| | | I _F = 300 A | | | | 1.36 | V |
| | | $I_{\rm F} = 150 \rm A$ | T _{VJ} = 125 °C | | | 1.05 | V |
| | | $I_{F} = 300 \text{ A}$ | | | | 1.33 | V |
| FAV | average forward current | T _c = 110°C | $T_{VJ} = 150 ^{\circ}\text{C}$ | | | 150 | Α |
| | | rectangular d = 0.5 | | | | | 1 |
| V _{F0} | threshold voltage | | $T_{vJ} = 150^{\circ}C$ | | | 0.78 | V |
| r _F | slope resistance } for power | loss calculation only | | | | 1.8 | mΩ |
| R _{thJC} | thermal resistance junction to ca | ase | | | | 0.2 | K/W |
| R _{thCH} | thermal resistance case to heats | sink | | | 0.1 | | K/W |
| P _{tot} | total power dissipation | | $T_c = 25^{\circ}C$ | | | 620 | W |
| I _{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^{\circ}C$ | | | 3.00 | kA |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 3.24 | kA |
| | | t = 10 ms; (50 Hz), sine | $T_{vJ} = 150^{\circ}C$ | | | 2.55 | kA |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 2.76 | kA |
| l²t | value for fusing | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^{\circ}C$ | | | 45.0 | kA²s |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 43.7 | kA²s |
| | | t = 10 ms; (50 Hz), sine | T _{vJ} = 150°C | | | 32.5 | kA ² s |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0 V$ | | | 31.6 | kA²s |
| C | junction capacitance | V_{R} = 400 V; f = 1 MHz | $T_{vJ} = 25^{\circ}C$ | | 60 | | pF |

20191129b



| Package | e SOT-227B (minibloc) | | | | I | Rating | S | |
|-----------------------------|------------------------------|-----------------------------------|-----------------------------|------|------|--------|------|------|
| Symbol | Definition | Conditions | | | min. | typ. | max. | Unit |
| I _{RMS} | RMS current | per terminal 1) | | | | | 150 | A |
| T _{vj} | virtual junction temperature | | | | -40 | | 150 | °C |
| T _{op} | operation temperature | | | | -40 | | 125 | °C |
| T _{stg} | storage temperature | | | | -40 | | 150 | °C |
| Weight | | | | | | 30 | | g |
| M _D | mounting torque | | | | 1.1 | | 1.5 | Nm |
| M _T | terminal torque | | | | 1.1 | | 1.5 | Nm |
| d _{Spp/App} | oroonago distanco on surface | e striking distance through air | terminal to terminal | 10.5 | 3.2 | | | mm |
| d _{Spb/Apb} | creepage ustance on surface | sinking distance through an | terminal to backside | 8.6 | 6.8 | | | mm |
| V | isolation voltage | t = 1 second | | | 3000 | | | V |
| | t = 1 minute | | 50/60 Hz, RMS; lıso∟ ≤ 1 mA | | 2500 | | | V |

¹⁾ I_{must} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.



Part description

- D = Diode
- M = Standard Rectifier
- A = (up to 1800V)
- 150 = Current Rating [A]
- E = Single Diode 1600 = Reverse Voltage [V]
- NA = SOT-227B (minibloc)

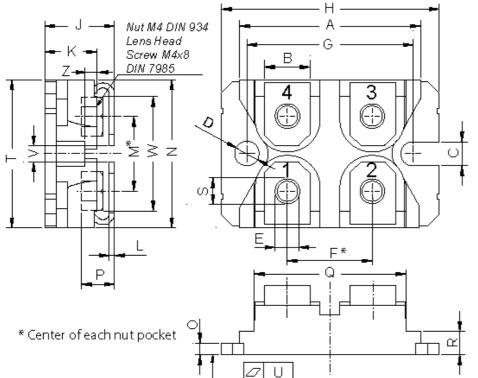
| Standard DMA150E1600NA DMA150E1600NA Tube 10 508942 | Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|---|----------|-----------------|--------------------|---------------|----------|----------|
| | Standard | DMA150E1600NA | DMA150E1600NA | Tube | 10 | 508942 |

| Equiva | lent Circuits for | Simulation | * on die level | $T_{VJ} = 150^{\circ}C$ |
|------------------------------|--------------------|------------|----------------|-------------------------|
| | - R o - | Rectifier | | |
| V _{0 max} | threshold voltage | 0.78 | | V |
| $\mathbf{R}_{0 \text{ max}}$ | slope resistance * | 1 | | mΩ |

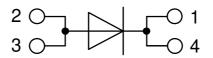
20191129b



Outlines SOT-227B (minibloc)



| Dim. | Millimeter | | Inches | | |
|------|------------|-------|--------|-------|--|
| Dim. | min | max | min | max | |
| Α | 31.50 | 31.88 | 1.240 | 1.255 | |
| В | 7.80 | 8.20 | 0.307 | 0.323 | |
| С | 4.09 | 4.29 | 0.161 | 0.169 | |
| D | 4.09 | 4.29 | 0.161 | 0.169 | |
| Е | 4.09 | 4.29 | 0.161 | 0.169 | |
| F | 14.91 | 15.11 | 0.587 | 0.595 | |
| G | 30.12 | 30.30 | 1.186 | 1.193 | |
| Н | 37.80 | 38.23 | 1.488 | 1.505 | |
| J | 11.68 | 12.22 | 0.460 | 0.481 | |
| К | 8.92 | 9.60 | 0.351 | 0.378 | |
| L | 0.74 | 0.84 | 0.029 | 0.033 | |
| Μ | 12.50 | 13.10 | 0.492 | 0.516 | |
| Ν | 25.15 | 25.42 | 0.990 | 1.001 | |
| 0 | 1.95 | 2.13 | 0.077 | 0.084 | |
| Р | 4.95 | 6.20 | 0.195 | 0.244 | |
| Q | 26.54 | 26.90 | 1.045 | 1.059 | |
| R | 3.94 | 4.42 | 0.155 | 0.167 | |
| S | 4.55 | 4.85 | 0.179 | 0.191 | |
| Т | 24.59 | 25.25 | 0.968 | 0.994 | |
| U | -0.05 | 0.10 | -0.002 | 0.004 | |
| V | 3.20 | 5.50 | 0.126 | 0.217 | |
| W | 19.81 | 21.08 | 0.780 | 0.830 | |
| Ζ | 2.50 | 2.70 | 0.098 | 0.106 | |
| | | | | | |

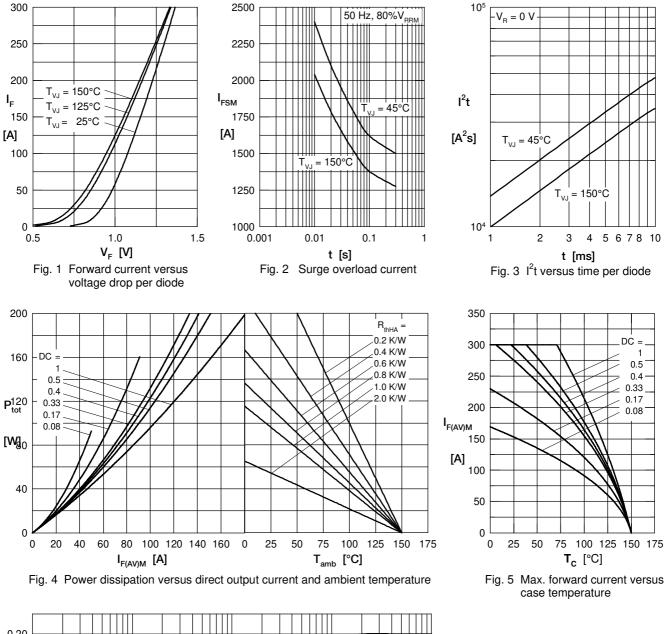


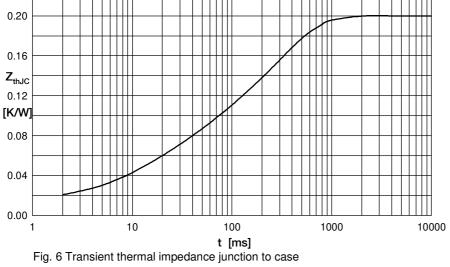
IXYS reserves the right to change limits, conditions and dimensions.

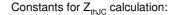
20191129b



Rectifier







| i | R _{thi} (K/W) | t _i (s) |
|---|------------------------|--------------------|
| 1 | 0.017 | 0.01 |
| 2 | 0.013 | 0.00001 |
| 3 | 0.010 | 0.01 |
| 4 | 0.04 | 0.04 |
| 5 | 0.12 | 0.3 |
| | | |

IXYS reserves the right to change limits, conditions and dimensions.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by IXYS manufacturer:

Other Similar products are found below :

 70HFR40
 RL252-TP
 150KR30A
 1N5397
 NTE5841
 NTE6038
 SCF5000
 1N4002G
 1N4005-TR
 JANS1N6640US
 481235F

 RRE02VS6SGTR
 067907F
 MS306
 70HF40
 T85HFL60S02
 US2JFL-TP
 A1N5404G-G
 ACGRA4007-HF
 ACGRB207-HF

 CLH03(TE16L,Q)
 ACGRC307-HF
 ACEFC304-HF
 NTE6356
 NTE6359
 NTE6002
 NTE6023
 NTE6039
 NTE6077
 85HFR60
 40HFR60

 VS-88-7272PBF
 70HF120
 85HFR80
 D126A45C
 SCF7500
 D251N08B
 SCHJ22.5K
 SM100
 SCPA2
 SCH10000
 SDHD5K
 VS

 12FL100S10
 ACGRA4001-HF
 D1821SH45T
 PR
 D1251S45T
 NTE5990
 NTE6162
 NTE5998